



UT3400

Power MOSFET

**5.8A, 30V N-CHANNEL
ENHANCEMENT MODE POWER
MOSFET**

■ **DESCRIPTION**

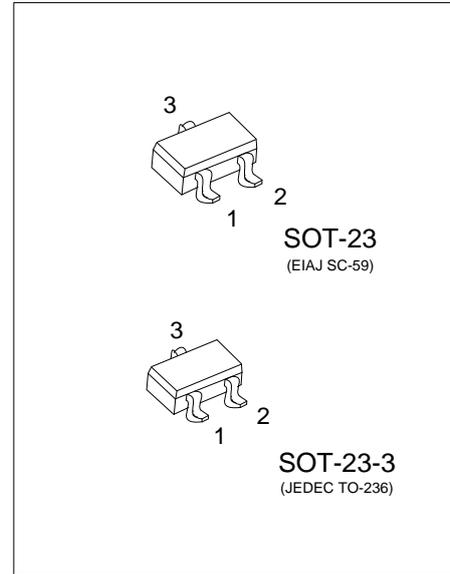
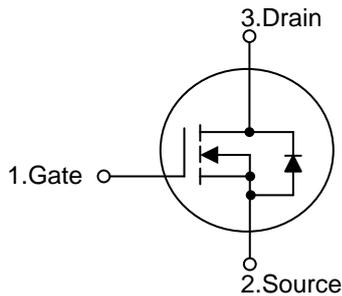
The UTC **UT3400** is an N-ch enhancement MOSFET providing the customers with perfect $R_{DS(ON)}$ and low gate charge. This device can be operated with 2.5V low gate voltage.

The UTC **UT3400** is optimized for applications, such as a load switch or in PWM.

■ **FEATURES**

- * $R_{DS(ON)} \leq 28\text{ m}\Omega$ @ $V_{GS}=10\text{V}$, $I_D=5.8\text{A}$
- $R_{DS(ON)} \leq 33\text{ m}\Omega$ @ $V_{GS}=4.5\text{V}$, $I_D=5.0\text{A}$
- $R_{DS(ON)} \leq 52\text{ m}\Omega$ @ $V_{GS}=2.5\text{V}$, $I_D=4.0\text{A}$

■ **SYMBOL**



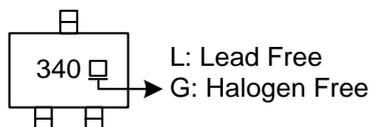
■ **ORDERING INFORMATION**

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
UT3400L-AE2-R	UT3400G-AE2-R	SOT-23-3	G	S	D	Tape Reel
UT3400L-AE3-R	UT3400G-AE3-R	SOT-23	G	S	D	Tape Reel

Note: Pin Assignment: G: Gate S: Source D: Drain

<p>UT3400G-AE2-R</p>	<p>(1) R: Tape Reel</p> <p>(2) AE2: SOT-23-3, AE3: SOT-23</p> <p>(3) G: Halogen Free and Lead Free, L: Lead Free</p>
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■ **MARKING**



■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Drain-Source Voltage	V _{DS}	30	V
Gate-Source Voltage	V _{GS}	±12	V
Continuous Drain Current	I _D	5.8	A
Pulsed Drain Current (Note 2)	I _{DM}	30	A
Power Dissipation	P _D	1.4	W
Junction Temperature	T _J	+150	°C
Storage Temperature	T _{STG}	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating : Pulse width limited by maximum junction temperature.

3. Pulse width ≤300μs, duty cycle≤0.5%.

■ THERMAL DATA

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT
Junction to Ambient (Note)	θ _{JA}		85	125	°C/W

Note: Surface mounted on 1 in² copper pad of FR4 board with 2oz.

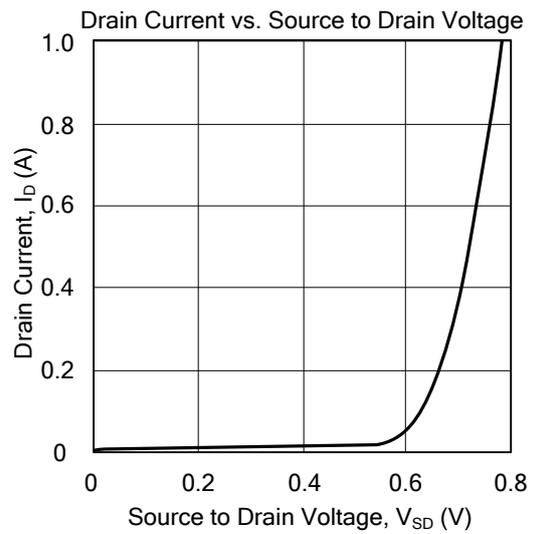
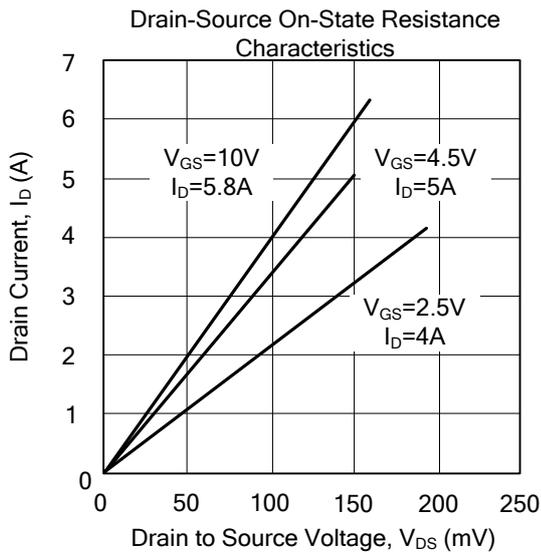
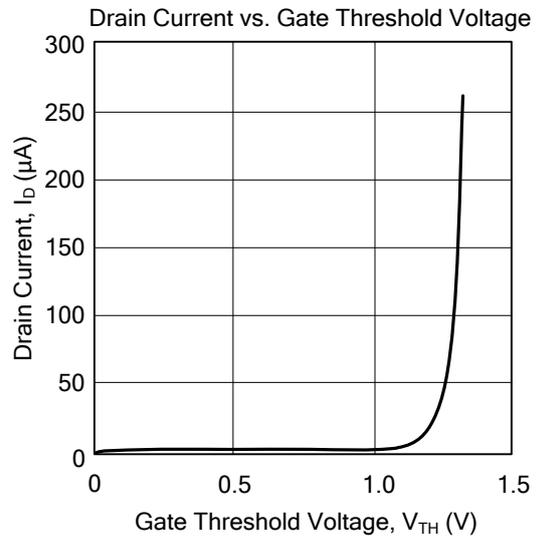
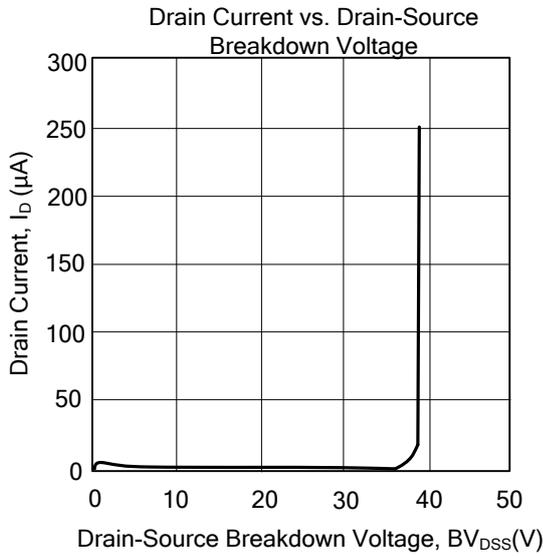
■ ELECTRICAL CHARACTERISTICS (T_J=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250μA	30			V
Drain-Source Leakage Current	I _{DSS}	V _{DS} =24V, V _{GS} =0V			1	μA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±12V, V _{DS} =0V			100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	V _{GS(TH)}	V _{DS} =V _{GS} , I _D =250μA	0.7	1.1	1.4	V
On-State Drain Current	I _{D(ON)}	V _{DS} =5V, V _{GS} =4.5V	30			A
Drain to Source On-state Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =5.8A		22.8	28	mΩ
		V _{GS} =4.5V, I _D =5A		27.3	33	mΩ
		V _{GS} =2.5V, I _D =4 A		43.3	52	mΩ
DYNAMIC PARAMETERS						
Input Capacitance	C _{ISS}	V _{DS} =15V, V _{GS} =0V, f=1MHz		823		pF
Output Capacitance	C _{OSS}			99		pF
Reverse Transfer Capacitance	C _{RSS}			77		pF
Gate Resistance	R _G	V _{GS} =0V, V _{DS} =0V, f=1MHz		1.2		Ω
SWITCHING PARAMETERS						
Total Gate Charge	Q _G	V _{GS} =4.5V, V _{DS} =15V, I _D =5.8A		9.7		nC
Gate Source Charge	Q _{GS}			1.6		nC
Gate Drain Charge	Q _{GD}			3.1		nC
Turn-ON Delay Time	t _{D(ON)}	V _{GS} =10V, V _{DS} =15V R _L =2.7Ω, R _{GEN} =6Ω		5.5		ns
Turn-ON Rise Time	t _R			5.1		ns
Turn-OFF Delay Time	t _{D(OFF)}			37		ns
Turn-OFF Fall-Time	t _F			4.2		ns
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS						
Diode Continuous Forward Current (Note 1)	I _S				2.5	A
Drain-Source Diode Forward Voltage	V _{SD}	I _S =1A, V _{GS} =0V		0.71	1	V
Reverse Recovery Time	t _{rr}	I _F =5A, dI/dt=100A/μs		16		ns
Reverse Recovery Charge	Q _{rr}				8.9	

Notes: 1. Repetitive Rating : Pulse width limited by maximum junction temperature.

2. Pulse width ≤300μs, duty cycle≤0.5%.

■ TYPICAL CHARACTERISTICS



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